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APPLICATION NO. FILING DATE FIRST NAMED INVENTOR ATTORNEY DOCKET NO. 09/208.325 12/09/98 SHIELDS J 120998 **EXAMINER** MM92/0406 LAW OFFICE OF H DONALD NELSON NGUYEN. T 5492 LIVORNO COURT **ART UNIT** PAPER NUMBER **SAN JOSE CA 95138** 2813 **DATE MAILED:**

Please find below and/or attached an Office communication concerning this application or proceeding.

Commissioner of Patents and Trademarks

04/06/00 .



Office Action Summary

Application No. 09/208,325 Applicant(s)

Shields et al.

Examiner

Thanh Nguyen

Group Art Unit 2813



Responsive to communication(s) filed on <u>Dec 9, 1998</u>	•
This action is FINAL.	
Since this application is in condition for allowance except for in accordance with the practice under Ex parte Quayle, 193	35 C.D. 11; 453 O.G. 213.
A shortened statutory period for response to this action is set to solve the solve solve solve the mailing date of this communication. Failure application to become abandoned. (35 U.S.C. § 133). Extens 37 CFR 1.136(a).	to respond within the period for response will cause the
Disposition of Claims	
Of the above, claim(s) none	is/are withdrawn from consideration.
Claim(s)	is/are allowed.
	is/are rejected.
☐ Claim(s)	is/are objected to.
☐ Claims	
Application Papers X See the attached Notice of Draftsperson's Patent Drawin	
☐ The drawing(s) filed on is/are object	cted to by the Examiner.
☐ The proposed drawing correction, filed on	is □approved □disapproved.
\square The specification is objected to by the Examiner.	
☐ The oath or declaration is objected to by the Examiner.	
Priority under 35 U.S.C. § 119 Acknowledgement is made of a claim for foreign priority All Some* None of the CERTIFIED copies	
received.	
☐ received in Application No. (Series Code/Serial No.	
\square received in this national stage application from th	
*Certified copies not received:	
☐ Acknowledgement is made of a claim for domestic prio	rity under 30 U.S.C. 3 113(e).
Attachment(s) Notice of References Cited, PTO-892 Information Disclosure Statement(s), PTO-1449, Paper	No(s)
☐ Interview Summary, PTO-413☒ Notice of Draftsperson's Patent Drawing Review, PTO-5	948
□ Notice of Informal Patent Application, PTO-152	
SEE OFFICE ACTION ON	N THE FOLLOWING PAGES

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DETAILED ACTION

Claim Rejections - 35 U.S.C. § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless --

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

Claims 1-5 are rejected under 35 U.S.C. 102(b) as being anticpated by the Admitted Prior Art.

Referring to figures 1a-1I, the Admitted Prior Art teaches a method of manufacturing a semiconductor device comprises: forming a final metal layer (104) over the interlayer dielectric (102), forming a TiN layer (106) over the metal layer, forming a layer of photoresist (108) over the TiN layer, patterning and developing the first layer of photoresist exposing portions of the TiN layer, etching in the layer of TiN and the final layer of metal exposing portions of the interlay dielectric layer, removing the first layer of photoresist and the layer of TiN, depositing a blanket layer (114), forming a second photoresist layer (116) on the blanket layer of interlayer dielectric; patterning and developing the second layer of the photoresist layer exposing portions of blanket layer of interlayer dielectric overlying metal structures; and etching the exposed portion of the blanket layer of interlayer dielectric down to the metal structures, removing the second layer of the photoresist (see figures 1a-1I of the Admitted Prior art and related text).

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Claim Rejections - 35 U.S.C. § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 1-5 are rejected under 35 U.S.C. 103(a) as being unpatentable over the Admitted Prior Art.

Referring to figures 1a-1I, the Admitted Prior Art teaches a method of manufacturing a semiconductor device comprises: forming a final metal layer (104) over the interlayer dielectric (102), forming a TiN layer (106) over the metal layer, forming a layer of photoresist (108) over the TiN layer, patterning and developing the first layer of photoresist exposing portions of the TiN layer, etching in the layer of TiN and the final layer of metal exposing portions of the interlay dielectric layer, removing the first layer of photoresist and the layer of TiN, depositing a blanket layer (114), forming a second photoresist layer (116) on the blanket layer of interlayer dielectric; patterning and developing the second layer of the photoresist layer exposing portions of blanket layer of interlayer dielectric overlying metal structures; and etching the exposed portion of the blanket layer of interlayer dielectric down to the metal structures, removing the second layer of the photoresist (see figures 1a-1I of the Admitted Prior art and related text).

However, the reference does not teach etching the photoresist layer and TiN layer by suing fluorine containing gas chemistry at an elevated temperature.

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The examiner takes Official Notice that the embodiment described in claim 5 would have

been obvious to skilled worker in the art at the time the invention was made because determining

the optimum material for etching the layer only involved routine skill in the art (see MPEP

2144.03).

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner

should be directed to Thanh Nguyen whose telephone number is (703) 308-9439. The examiner

can normally be reached on Monday-Thursday from 7:30AM to 4:30PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor,

Charles Bowers, can be reached on (703) 308-2417. The fax phone number for this Group is

(703) 308-7722.

Any inquiry of a general nature or relating to the status of this application or proceeding

should be directed to the Group receptionist whose telephone number is (703) 308-0956.

Thanh Nguyen

April 4, 2000

Charles Bowers.

Supervisory Patent Examiner Technology Center 2800 Page 4